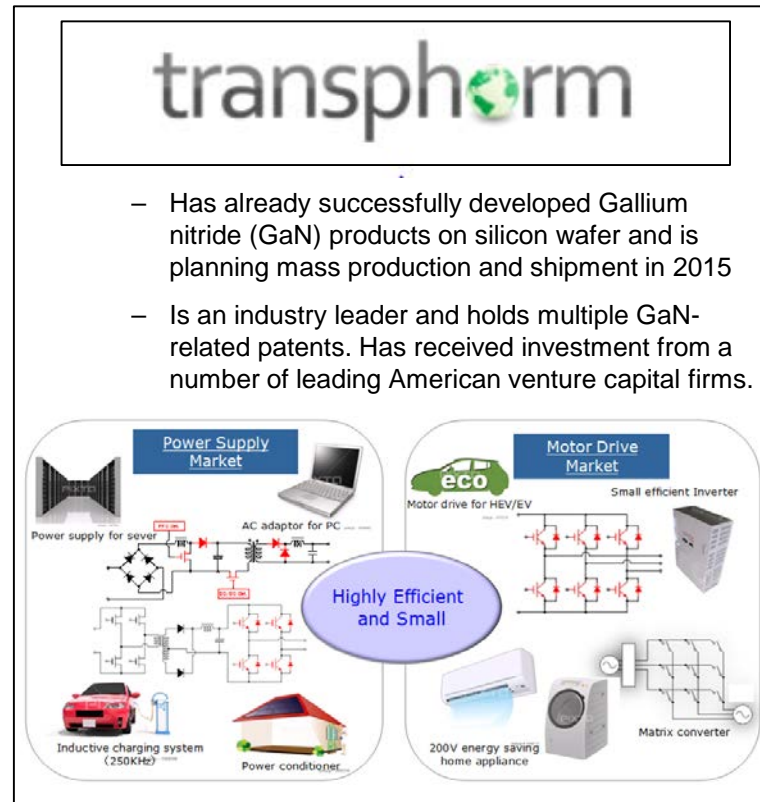


Target : Transphorm, Inc.

Outline : Development, manufacture and sales of GaN power semiconductors

Authorized investment : ¥3 billion (maximum)



Investment

**Venture Capital
Private Equity**

R&D cooperation

UCSB
UNIVERSITY OF CALIFORNIA
SANTA BARBARA

**Energy efficient and greatly reduces power loss.
Contributes to low-carbon society**

Nihon Inter Electronics Corporation

Investment

Cooperation in sales and
manufacture